

DDR 14-Bit Registered Buffer

ICSSSTV16857C

Recommended Applications:

- DDR Memory Modules
- Provides complete DDR DIMM logic solution with ICS93V857 or ICS95V857
- SSTL_2 compatible data registers

Product Features:

- Differential clock signal
- Meets SSTL_2 signal data
- Supports SSTL_2 class I & II specifications
- Low-voltage operation
 - $V_{DD} = 2.3V$ to $2.7V$
- 48 pin TSSOP package

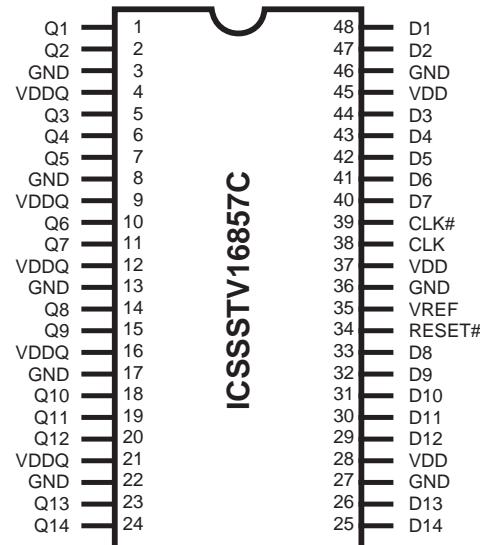
Truth Table¹

Inputs				Q Outputs
RESET#	CLK	CLK#	D	Q
L	X or Floating	X or Floating	X or Floating	L
H	↑	↓	H	H
H	↑	↓	L	L
H	L or H	L or H	X	$Q_0^{(2)}$

Notes:

1. H = High Signal Level
L = Low Signal Level
↑ = Transition LOW-to-HIGH
↓ = Transition HIGH -to LOW
X = Irrelevant
2. Output level before the indicated steady state input conditions were established.

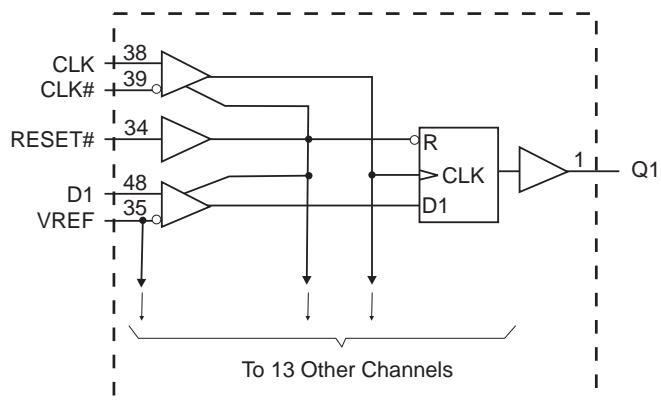
Pin Configuration



48-Pin TSSOP & TVSOP

6.10 mm. Body, 0.50 mm. pitch = TSSOP
4.40 mm. Body, 0.40 mm. pitch = TVSOP (TVSOP)

Block Diagram



General Description

The 14-bit ICSSSTV16857C is a universal bus driver designed for 2.3V to 2.7V V_{DD} operation and SSTL_2 I/O levels, except for the LVCMOS RESET# input.

Data flow from D to Q is controlled by the differential clock (CLK/CLK#) and a control signal (RESET#). The positive edge of CLK is used to trigger the data flow and CLK# is used to maintain sufficient noise margins where as RESET#, an LVCMOS asynchronous signal, is intended for use at the time of power-up only. ICSSSTV16857C supports low-power standby operation. A logic level "Low" at RESET# assures that all internal registers and outputs (Q) are reset to the logic "Low" state, and all input receivers, data (D) and clock (CLK/CLK#) are switched off. Please note that RESET# must always be supported with LVCMOS levels at a valid logic state because VREF may not be stable during power-up.

To ensure that outputs are at a defined logic state before a stable clock has been supplied, RESET# must be held at a logic "Low" level during power up.

In the DDR DIMM application, RESET# is specified to be completely asynchronous with respect to CLK and CLK#. Therefore, no timing relationship can be guaranteed between the two signals. When entering a low-power standby state, the register will be cleared and the outputs will be driven to a logic "Low" level quickly relative to the time to disable the differential input receivers. This ensures there are no glitches on the output. However, when coming out of low-power standby state, the register will become active quickly relative to the time to enable the differential input receivers. When the data inputs are at a logic level "Low" and the clock is stable during the "Low"-to-"High" transition of RESET# until the input receivers are fully enabled, the design ensures that the outputs will remain at a logic "Low" level.

Pin Configuration

PIN NUMBER	PIN NAME	TYPE	DESCRIPTION
24, 23, 20, 19, 18, 15, 14, 11, 10, 7, 6, 5, 2, 1	Q (14:1)	OUTPUT	Data output
3, 8, 13, 22, 27, 36, 46	GND	PWR	Ground
4, 9, 12, 16, 21	VDDQ	PWR	Output supply voltage
25, 26, 29, 30, 31, 32, 33, 40, 41, 42, 43, 44, 47, 48	D (14:1)	INPUT	Data input
38	CLK	INPUT	Positive clock input
39	CLK#	INPUT	Negative clock input
28, 37, 45	VDD	PWR	Core supply voltage
34	RESET#	INPUT	Reset (active low)
35	VREF	INPUT	Input reference voltage

Absolute Maximum Ratings

Storage Temperature	-65°C to +150°C
Supply Voltage	-0.5 to 3.6V
Input Voltage ¹	-0.5 to $V_{DD} + 0.5$
Output Voltage ^{1,2}	-0.5 to $V_{DDQ} + 0.5$
Input Clamp Current	± 50 mA
Output Clamp Current	± 50 mA
Continuous Output Current	± 50 mA
V_{DD} , V_{DDQ} or GND Current/Pin	± 100 mA
Package Thermal Impedance ³	55°C/W

Notes:

1. The input and output negative voltage ratings may be excluded if the input and output clamp ratings are observed.
2. This current will flow only when the output is in the high state level $V_O > V_{DDQ}$.
3. The package thermal impedance is calculated in accordance with JESD 51.

Stresses above those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only and functional operation of the device at these or any other conditions above those listed in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Recommended Operating Conditions

PARAMETER	DESCRIPTION		MIN	TYP	MAX	UNITS
V_{DD}	Supply Voltage		2.3	2.5	2.7	V
V_{DDQ}	I/O Supply Voltage		2.3	2.5	2.7	
V_{REF}	Reference Voltage		1.15	1.25	1.35	
V_{TT}	Termination Voltage		$V_{REF} - 0.04$	V_{REF}	$V_{REF} + 0.04$	
V_I	Input Voltage		0		V_{DDQ}	
V_{IH} (DC)	DC Input High Voltage	Data Inputs	$V_{REF} + 0.15$			
V_{IH} (AC)	AC Input High Voltage		$V_{REF} + 0.31$			
V_{IL} (DC)	DC Input Low Voltage				$V_{REF} - 0.15$	
V_{IL} (AC)	AC Input Low Voltage				$V_{REF} - 0.31$	
V_{IH}	Input High Voltage Level	RESET#	1.7			mA
V_{IL}	Input Low Voltage Level				0.7	
V_{ICR}	Common mode Input Range	CLK, CLK#	0.97		1.53	
V_{ID}	Differential Input Voltage		0.36			
V_{IX}	Cross Point Voltage of Differential Clock Pair		$(V_{DDQ}/2) - 0.2$		$(V_{DDQ}/2) + 0.2$	
I_{OH}	High-Level Output Current				-20	
I_{OL}	Low-Level Output Current				20	
T_A	Operating Free-Air Temperature		0		70	°C

¹Guaranteed by design, not 100% tested in production.

Electrical Characteristics - DC $T_A = 0 - 70^\circ C$; $V_{DD} = 2.5 \pm 0.2V$, $V_{DDQ} = 2.5 \pm 0.2V$; (unless otherwise stated)

SYMBOL	PARAMETERS	CONDITIONS	V_{DDQ}	MIN	TYP	MAX	UNITS
V_{IK}		$I_I = -18mA$	2.3V			-1.2	V
V_{OH}		$I_{OH} = -100\mu A$	2.3V-2.7V	$V_{DDQ} - 0.2$			
		$I_{OH} = -16mA$	2.3V	1.95			
V_{OL}		$I_{OL} = 100\mu A$	2.3V-2.7V			0.2	
		$I_{OL} = 16mA$	2.3V			0.35	
I_I	All Inputs	$V_I = V_{DD}$ or GND	2.7V			± 5	μA
I_{DD}	Standby (Static)	RESET# = GND	I _O = 0			0.01	μA
	Operating (Static)	$V_I = V_{IH(AC)}$ or $V_{IL(AC)}$, RESET# = V_{DD}			52		mA
I_{DDD}	Dynamic operating (clock only)	RESET# = V_{DD} , $V_I = V_{IH(AC)}$ or $V_{IL(AC)}$, CLK and CLK# switching 50% duty cycle.			75		$\mu A/\text{clock}$ MHz
	Dynamic Operating (per each data input)	RESET# = V_{DD} , $V_I = V_{IH(AC)}$ or $V_{IL(AC)}$, CLK and CLK# switching 50% duty cycle. One data input switching at half clock frequency, 50% duty cycle			15		$\mu A/\text{clock}$ MHz/data
r_{OH}	Output High	$I_{OH} = -20mA$	2.3V-2.7V	7	13.5	20	Ω
r_{OL}	Output Low	$I_{OL} = 20mA$	2.3V-2.7V	7	13	20	Ω
$r_{O(D)}$	$[r_{OH} - r_{OL}]$ each separate bit	$I_O = 20mA$, $T_A = 25^\circ C$	2.5V			4	Ω
C_i	Data Inputs	$V_I = V_{REF} \pm 350mV$	2.5V	2.5		3.5	pF
	CLK and CLK#	$V_{ICR} = 1.25V$, $V_{I(PP)} = 360mV$		2.5		3.5	

Notes:

1 - Guaranteed by design, not 100% tested in production.

Timing Requirements¹

(over recommended operating free-air temperature range, unless otherwise noted)

SYMBOL	PARAMETERS		$V_{DDQ} = 2.5 \pm 0.2V$		UNITS
			MIN	MAX	
f_{clock}	Clock frequency			200	MHz
t_{PD}	Clock to output time		1.7	2.5	ns
t_{RST}	Reset to output time			3.5	ns
t_{SL}	Output slew rate		1	4	V/ns
t_S	Setup time, fast slew rate ^{2&4}	Data before CLK↑, CLK#↓	0.4		ns
	Setup time, slow slew rate ^{3&4}		0.5		ns
T_h	Hold time, fast slew rate ^{2&4}	Data after CLK↑, CLK#↓	0.4		ns
	Hold time, slow slew rate ^{3&4}		0.5		ns

Notes: 1 - Guaranteed by design, not 100% tested in production.

2 - For data signal input slew rate $\geq 1V/ns$.

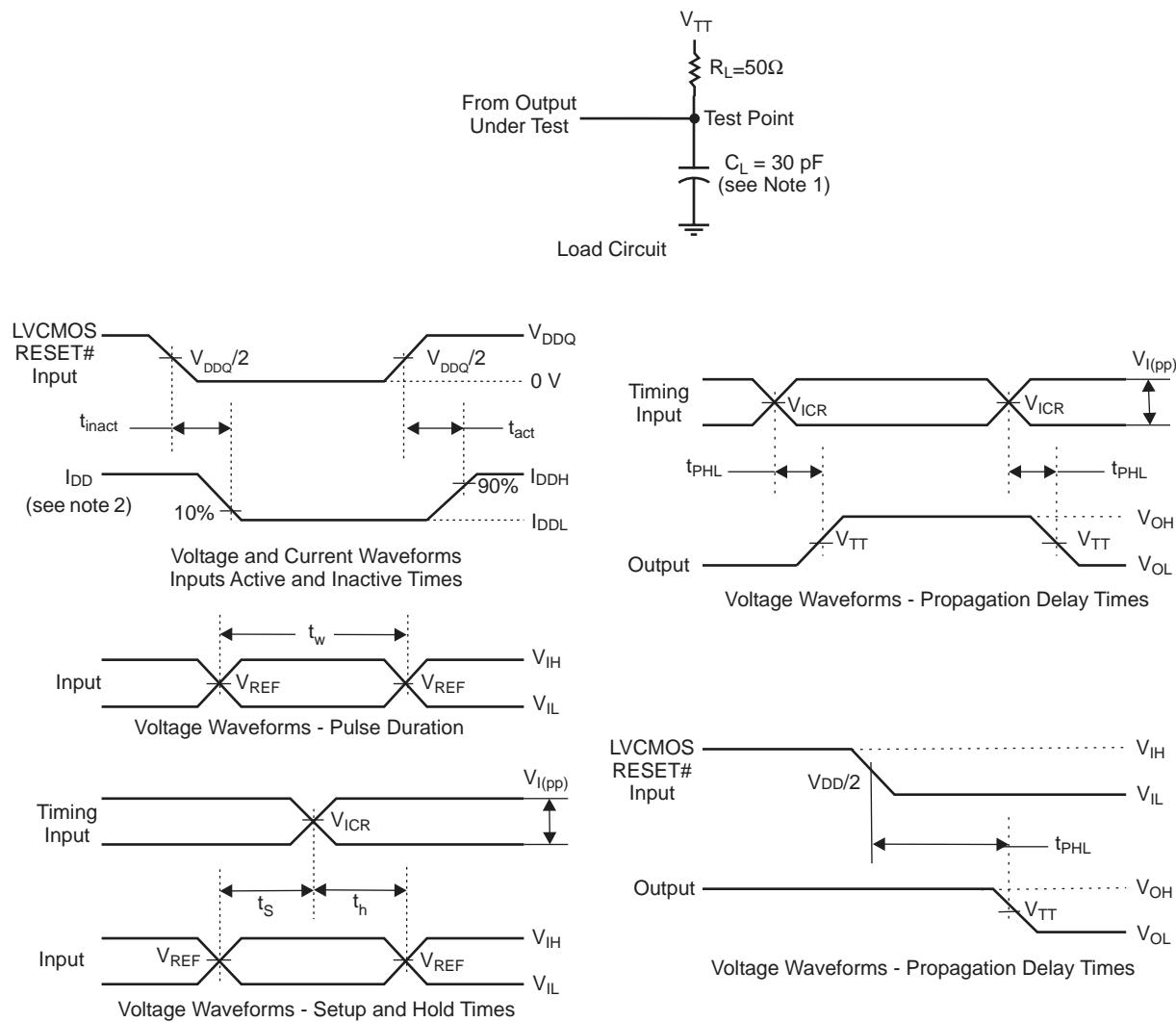
3 - For data signal input slew rate $\geq 0.5V/ns$ and $< 1V/ns$.

4 - CLK, CLK# signals input slew rates are $\geq 1V/ns$.

Switching Characteristics

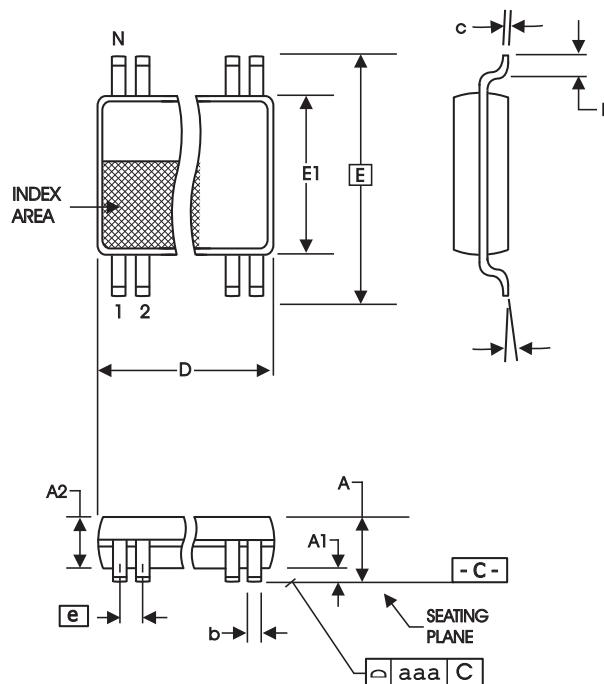
(over recommended operating free-air temperature range, unless otherwise noted) (see Figure 1)

SYMBOL	From (Input)	To (Output)	$V_{DD} = 2.5V \pm 0.2V$			UNITS
			MIN	TYP	MAX	
f_{max}			200			MHz
t_{PD}	CLK, CLK#	Q	1.7	2.1	2.5	ns
t_{phl}	RESET#	Q			3.5	ns

Figure 1 - Parameter Measurement Information ($V_{DDQ} = 2.5V \pm 0.2V$)

Notes:

1. CL includes probe and jig capacitance.
2. I_{DD} tested with clock and data inputs held at V_{DDQ} or GND, and $I_O = 0$ mA.
3. All input pulses are supplied by generators having the following characteristics: PRR @10 MHz, $Z_0=50\Omega$, input slew rate = 1 V/ns $\pm 20\%$ (unless otherwise specified).
4. The outputs are measured one at a time with one transition per measurement.
5. $V_{TT} = V_{REF} = V_{DDQ}/2$
6. $V_{IH} = V_{REF} + 310\text{mV}$ (AC voltage levels) for differential inputs. $V_{IH} = V_{DDQ}$ for LVCMS input.
7. $V_{IL} = V_{REF} - 310\text{mV}$ (AC voltage levels) for differential inputs. $V_{IL} = \text{GND}$ for LVCMS input.
8. t_{PLH} and t_{PHL} are the same as t_{pd}



SYMBOL	In Millimeters COMMON DIMENSIONS		In Inches COMMON DIMENSIONS	
	MIN	MAX	MIN	MAX
A	--	1.20	--	.047
A1	0.05	0.15	.002	.006
A2	0.80	1.05	.032	.041
b	0.17	0.27	.007	.011
c	0.09	0.20	.0035	.008
D	SEE VARIATIONS		SEE VARIATIONS	
E	8.10 BASIC		0.319 BASIC	
E1	6.00	6.20	.236	.244
e	0.50 BASIC		0.020 BASIC	
L	0.45	0.75	.018	.030
N	SEE VARIATIONS		SEE VARIATIONS	
α	0°	8°	0°	8°
aaa	--	0.10	--	.004

VARIATIONS

N	D mm.		D (inch)	
	MIN	MAX	MIN	MAX
48	12.40	12.60	.488	.496

Reference Doc.: JEDEC Publication 95, MO-153

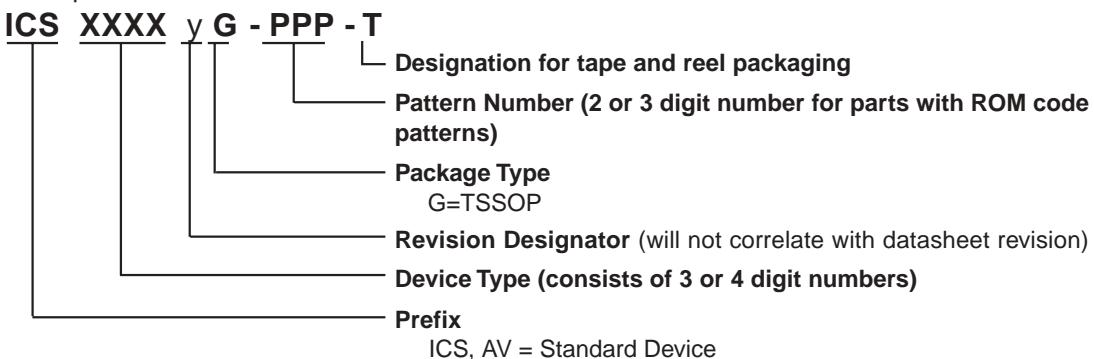
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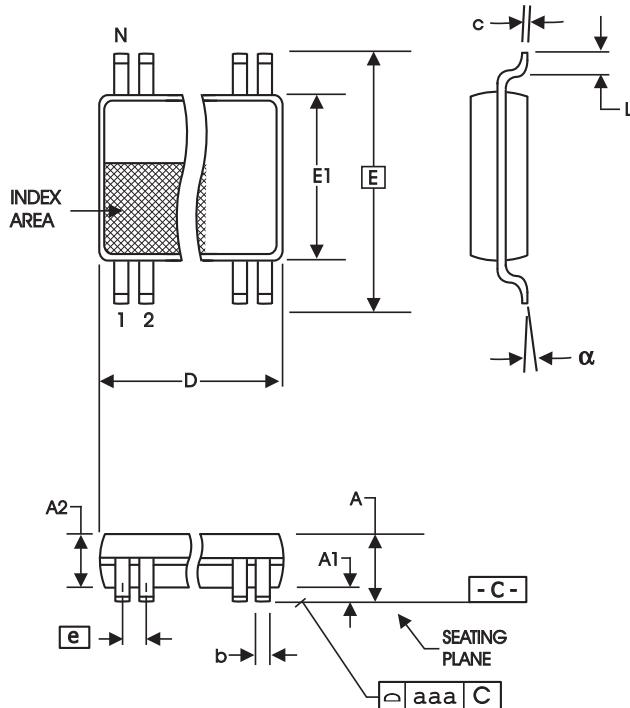
6.10 mm. Body, 0.50 mm. pitch TSSOP
(240 mil) (0.020 mil)

Ordering Information

ICSSSTV16857CG-T

Example:





SYMBOL	In Millimeters		In Inches	
	COMMON DIMENSIONS		COMMON DIMENSIONS	
	MIN	MAX	MIN	MAX
A	--	1.20	--	.047
A1	0.05	0.15	.002	.006
A2	0.80	1.05	.032	.041
b	0.13	0.23	.005	.009
c	0.09	0.20	.0035	.008
D	SEE VARIATIONS	SEE VARIATIONS	SEE VARIATIONS	SEE VARIATIONS
E	6.40 BASIC		0.252 BASIC	
E1	4.30	4.50	.169	.177
e	0.40 BASIC		0.016 BASIC	
L	0.45	0.75	.018	.030
N	SEE VARIATIONS	SEE VARIATIONS	SEE VARIATIONS	SEE VARIATIONS
α	0°	8°	0°	8°
aaa	--	0.08	--	.003

VARIATIONS

N	D mm.		D (inch)	
	MIN	MAX	MIN	MAX
48	9.60	9.80	.378	.386

Reference Doc.: JEDEC Publication 95, M O-153

10-0037

4.40 mm. Body, 0.40 mm. pitch TSSOP

(173 mil) (16 mil)

Ordering Information

ICSSSTV16857CL-T

Example:

ICS XXXX y L - PPP - T

Designation for tape and reel packaging

Pattern Number (2 or 3 digit number for parts with ROM code patterns)

Package Type

L = TSSOP (TSSOP)

Device Type (consists of 3 or 4 digit numbers)

Prefix

ICS, AV = Standard Device

ICSSSTV16857C

DDR 14-Bit Registered Buffer

TSD

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